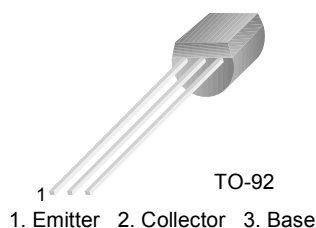


# BC638

## PNP Epitaxial Silicon Transistor

### Switching and Amplifier Applications

- Complement to BC637



### Absolute Maximum Ratings $T_a = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CER}$	Collector-Emitter Voltage at $R_{BE}=1K\Omega$	-60	V
$V_{CES}$	Collector-Emitter Voltage	-60	V
$V_{CEO}$	Collector-Emitter Voltage	-60	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current	-1	A
$I_{CP}$	Peak Collector Current	-1.5	A
$I_B$	Base Current	-100	mA
$P_C$	Collector Power Dissipation	1	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-65 ~ 150	$^\circ\text{C}$

### Electrical Characteristics $T_a = 25^\circ\text{C}$ unless otherwise noted

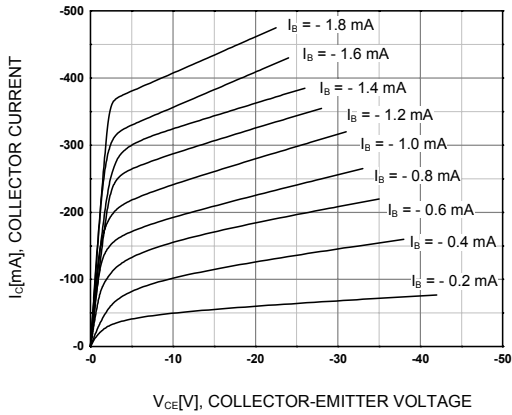
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = -10\text{mA}$ , $I_B = 0$	-60			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB} = -30\text{V}$ , $I_E = 0$			-0.1	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = -5\text{V}$ , $I_C = 0$			-0.1	$\mu\text{A}$
$h_{FE1}$ $h_{FE2}$ $h_{FE3}$	DC Current Gain	$V_{CE} = -2\text{V}$ , $I_C = -5\text{mA}$ $V_{CE} = -2\text{V}$ , $I_C = -150\text{mA}$ $V_{CE} = -2\text{V}$ , $I_C = -500\text{mA}$	25 40 25		160	
$V_{CE}(\text{sat})$	Collector-Emitter Saturation Voltage	$I_C = -500\text{mA}$ , $I_B = -50\text{mA}$			-0.5	V
$V_{BE}(\text{on})$	Base-Emitter On Voltage	$V_{CE} = -2\text{V}$ , $I_C = -500\text{mA}$			-1	V
$f_T$	Current Gain Bandwidth Product	$V_{CE} = -5\text{V}$ , $I_C = -10\text{mA}$ , $f = 50\text{MHz}$		100		MHz

**Package Marking and Ordering Information**

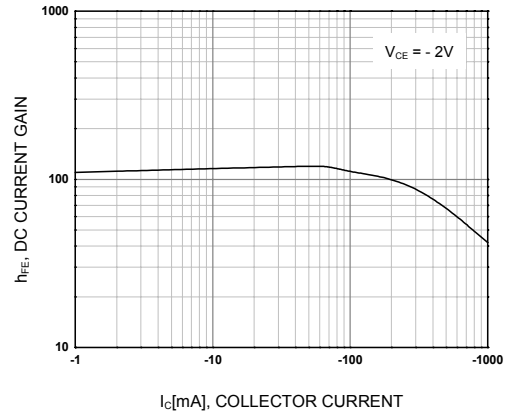
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
BC638	BC638BU	TO-92	--	--	10,000
BC638	BC638TA	TO-92	--	--	2,000
BC638	BC638TF	TO-92	--	--	2,000
BC638	BC638TFR	TO-92	--	--	2,000

## Typical Performance Characteristics

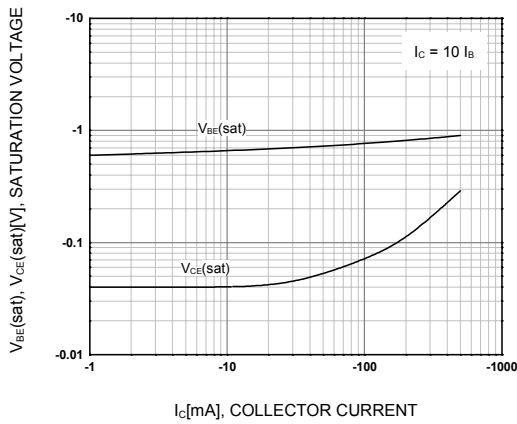
**Figure 1. Static Characteristic**



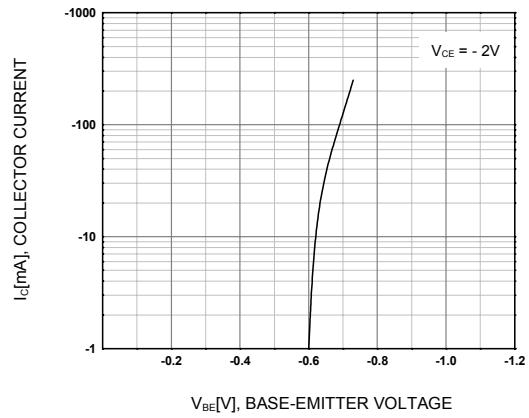
**Figure 2. DC Current Gain**



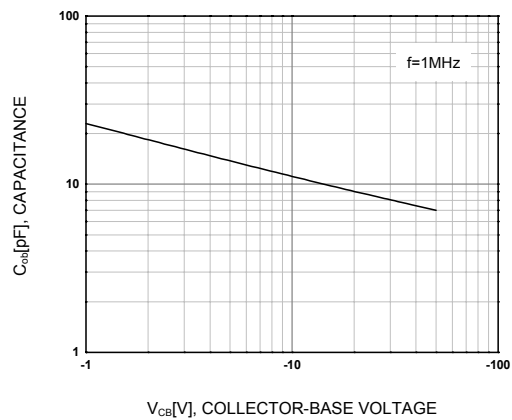
**Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage**



**Figure 4. Base-Emitter On Voltage**

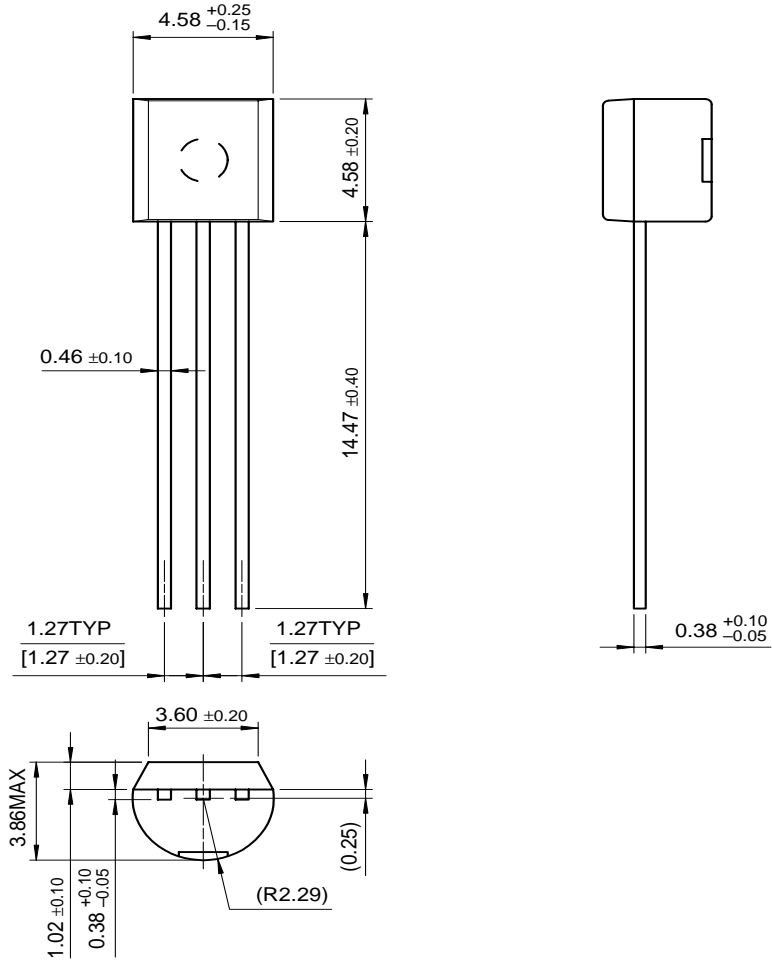


**Figure 5. Collector Output Capacitance**



Mechanical Dimensions

TO-92



Dimensions in Millimeters

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CROSSVOLT™	GTO™	MICROWIRE™	Quiet Series™	UHC™
DOME™	HiSeC™	MSX™	RapidConfigure™	UltraFET®
EcoSPARK™	I <sup>2</sup> C™	MSXPro™	RapidConnect™	UniFET™
E <sup>2</sup> C MOS™	i-Lo™	OCX™	μSerDes™	VCX™
EnSigna™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER®	Wire™
FACT™	IntelliMAX™	OPTOLOGIC®	SMART START™	
FACT Quiet Series™		OPTOPLANAR™	SPM™	
Across the board. Around the world.™		PACMAN™	Stealth™	
The Power Franchise®		POP™	SuperFET™	
Programmable Active Droop™		Power247™	SuperSOT™-3	
		PowerEdge™	SuperSOT™-6	

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Rev. I16